## -WILLAS

DB101S THRU DB107S

# SINGLE-PHASE GLASS PASSIVATED SILICON SURFACE MOUNT BRIDGE RECTIFIER VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere

#### **FEATURES**

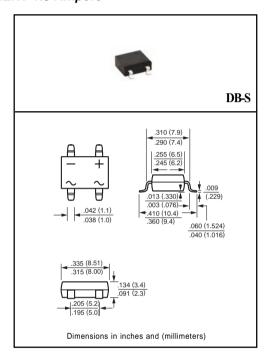
- \* Surge overload rating 50 amperes peak
- \* Ideal for printed circuit board
- \* Reliable low cost construction utilizing molded
- \* Glass passivated device
- \* Polarity symbols molded on body
- \* Mounting position: Any
- \* Weight: 0.378 grams
- \* RoHS product for packing code suffix "G"
  Halogen free product for packing code suffix "H"

#### **MECHANICAL DATA**

- \* Epoxy: Device has UL flammability classification 94V-0
- \* UL listed the recognized component directory, file #E195711

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



#### MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	DB101S	DB102S	DB103S	DB104S	DB105S	DB106S	DB107S	UNITS
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Output Current at TA = 40°C	lo	1							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	40							Amps
Rating for fusing (t<8.3ms)	I²t	6.6							A <sup>2</sup> S
Typical Thermal Resistance	RθJA	40							
(Note 2)	RθJL	15							°C/W
	Rθ <sub>JC</sub>	10							i
Operating and Storage Temperature Range	$T_J$ , $T_{STG}$	-55 to + 150						$^{\circ}$	

#### ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS		SYMBOL	DB101S	DB102S	DB103S	DB104S	DB105S	DB106S	DB107S	UNITS
Element at 1.0A DC Maximum Forward Voltage Drop per Bridge		V <sub>F</sub>	1.1						Volts	
Maximum Reverse Current at rated	@TA = 25°℃		5							uAmps
DC Blocking Voltage per element	@TA = 125℃	IR	0.5						mAmps	

NOTE: 1.Suffix "-s" Surface Mount for Dip Bridge.

### RATING AND CHARACTERISTIC CURVES (DB101S THRU DB107S)

FIG. 1 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PEAK FORWARD SURGE CURRENT, (A) 8.3ms Single Half Sine-Wave (JEDED Method) NUMBER OF CYCLES AT 60Hz

